# 74LV132-Q100 Quad 2-input NAND Schmitt trigger Rev. 1 — 11 November 2013

Product data sheet

# 1. General description

The 74LV132-Q100 is a low-voltage Si-gate CMOS device that is pin and function compatible with 74HC132-Q100 and 74HCT132-Q100.

The 74LV132-Q100 contains four 2-input NAND gates which accept standard input signals. These gates are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

The gate switches at different points for positive and negative-going signals. The difference between the positive voltage V<sub>T+</sub> and the negative voltage V<sub>T-</sub> is defined as the input hysteresis voltage V<sub>H</sub>.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

#### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide operating voltage: 1.0 V to 5.5 V
- Optimized for low voltage applications: 1.0 V to 3.6 V
- Accepts TTL input levels between V<sub>CC</sub> = 2.7 V and V<sub>CC</sub> = 3.6 V
- Typical output ground bounce < 0.8 V at  $V_{CC}$  = 3.3 V and  $T_{amb}$  = 25 °C
- Typical HIGH-level output voltage (V<sub>OH</sub>) undershoot: > 2 V at V<sub>CC</sub> = 3.3 V and  $T_{amb} = 25 \, ^{\circ}C$
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - ♦ MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Multiple package options

# 3. Applications

- Wave and pulse shapers for highly noisy environments
- Astable multivibrators
- Monostable multivibrators

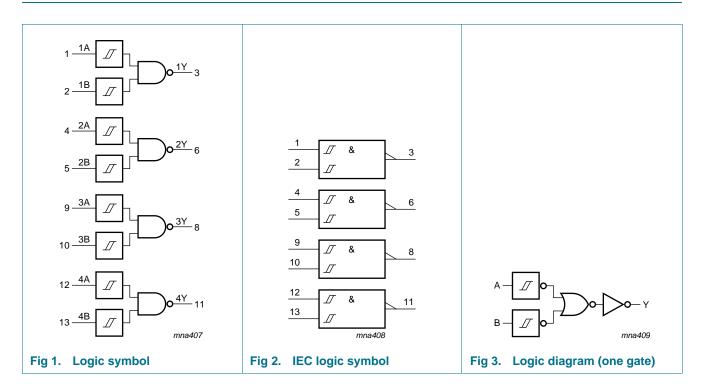


# 4. Ordering information

Table 1. Ordering information

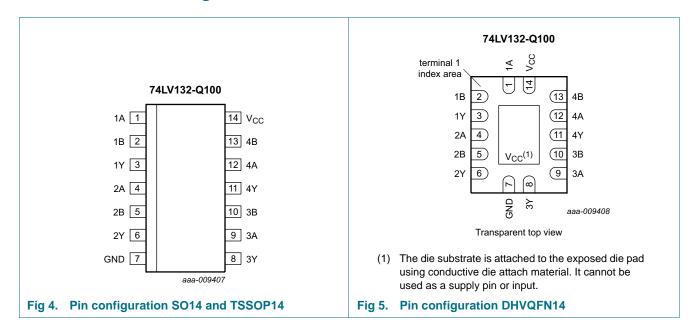
Type number	Package	Package										
	Temperature range	Name	Description	Version								
74LV132D-Q100	–40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1								
74LV132PW-Q100	–40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1								
74LV132BQ-Q100	–40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 $\times$ 3 $\times$ 0.85 mm	SOT762-1								

# 5. Functional diagram



# 6. Pinning information

# 6.1 Pinning



# 6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1A	1	data input
1B	2	data input
1Y	3	data output
2A	4	data input
2B	5	data input
2Y	6	data output
GND	7	ground (0 V)
3Y	8	data output
3A	9	data input
3B	10	data input
4Y	11	data output
4A	12	data input
4B	13	data input
V <sub>CC</sub>	14	supply voltage
·		

# 7. Functional description

#### Table 3. Function table

H = HIGH voltage level; L = LOW voltage level.

Input							
nA	nB	nY					
L	L	Н					
L	Н	Н					
Н	L	Н					
Н	Н	L					

# 8. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> -	±20	mA
I <sub>OK</sub>	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> -	±50	mA
Io	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-	±25	mA
I <sub>CC</sub>	supply current		-	50	mA
$I_{GND}$	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$			
	SO14 package		[2] -	500	mW
	TSSOP14 package		[3] _	500	mW
	DHVQFN14 package		<u>[4]</u> _	500	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>[2]</sup> Ptot derates linearly with 8 mW/K above 70 °C.

<sup>[3]</sup>  $P_{tot}$  derates linearly with 5.5 mW/K above 60 °C.

<sup>[4]</sup>  $P_{tot}$  derates linearly with 4.5 mW/K above 60 °C.

# 9. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{CC}$	supply voltage		<u>[1]</u>	1.0	3.3	5.5	V
VI	input voltage			0	-	$V_{CC}$	V
Vo	output voltage			0	-	$V_{CC}$	V
T <sub>amb</sub>	ambient temperature			-40	+25	+125	°C

<sup>[1]</sup> The static characteristics are guaranteed from  $V_{CC}$  = 1.2 V to  $V_{CC}$  = 5.5 V. LV devices are guaranteed to function down to  $V_{CC}$  = 1.0 V (with input levels GND or  $V_{CC}$ ).

# 10. Static characteristics

Table 6. Static characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	–40 °C to	Unit	
			Min	Typ[1]	Max	Min	Max	
$V_{OH}$	HIGH-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				'		'
		$I_{O} = -100 \mu A; V_{CC} = 1.2 V$	-	1.2	-	-	-	V
		$I_{O} = -100 \mu A; V_{CC} = 2.0 V$	1.8	2.0	-	1.8	-	V
		$I_{O} = -100 \mu A; V_{CC} = 2.7 V$	2.5	2.7	-	2.5	-	V
		$I_{O} = -100 \mu A; V_{CC} = 3.0 V$	2.8	3.0	-	2.8	-	V
		$I_{O} = -100 \mu A; V_{CC} = 4.5 V$	4.3	4.5	-	4.3	-	V
		$I_{O} = -6 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.4	2.82	-	2.2	-	V
		$I_{O} = -12 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.6	4.2	-	3.5	-	V
$V_{OL}$	LOW-level output voltage	$V_I = V_{T+}$ or $V_{T-}$						
		$I_O = 100 \mu A; V_{CC} = 1.2 V$	-	0	-	-	-	V
		$I_O = 100 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.2	-	0.2	V
		$I_O = 100 \mu A; V_{CC} = 2.7 V$	-	0	0.2	-	0.2	V
		$I_O = 100 \ \mu A; \ V_{CC} = 3.0 \ V$	-	0	0.2	-	0.2	V
		$I_O = 100 \mu A; V_{CC} = 4.5 V$	-	0	0.2	-	0.2	V
		$I_{O}$ = 6 mA; $V_{CC}$ = 3.0 V	-	0.25	0.40	-	0.50	V
		$I_{O}$ = 12 mA; $V_{CC}$ = 4.5 V	-	0.35	0.55	-	0.65	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	1.0	-	1.0	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	20.0	-	40	μΑ
$\Delta I_{CC}$	additional supply current	per input; $V_I = V_{CC} - 0.6 \text{ V}$ ; $V_{CC} = 2.7 \text{ V}$ to 3.6 V	-	-	500	-	850	μΑ
C <sub>I</sub>	input capacitance		-	3.5	-	-	-	pF

<sup>[1]</sup> Typical values are measured at  $T_{amb}$  = 25 °C.

# 11. Dynamic characteristics

**Table 7. Dynamic characteristics** *GND* = 0 *V*; *for test circuit, see Figure 7.* 

Symbol	Parameter	Conditions		-40	°C to +85	S °C	–40 °C t	o +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
$t_{pd}$	propagation delay	nA, nB to nY; see Figure 6	[2]						
		V <sub>CC</sub> = 1.2 V		-	65	-	-	-	ns
		$V_{CC} = 2.0 \text{ V}$		-	18	34	-	43	ns
		$V_{CC} = 2.7 V$		-	15	24	-	30	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } C_L = 15 \text{ pF}$	[3]	-	10	-	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	-	12	20	-	25	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[3]	-	9.0	14	-	17	ns
C <sub>PD</sub>	power dissipation capacitance	$C_L = 50 \text{ pF}; f_i = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$	[4]	-	24	-	-	-	pF

<sup>[1]</sup> All typical values are measured at  $T_{amb}$  = 25 °C.

[4]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$$
 where:

 $f_i$  = input frequency in MHz,  $f_o$  = output frequency in MHz

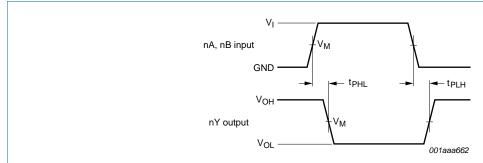
 $C_L$  = output load capacitance in pF

 $V_{CC}$  = supply voltage in V

N = number of inputs switching

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

### 12. Waveforms



Measurement points are given in Table 8.

 $V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

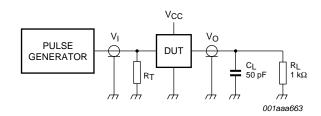
Fig 6. The input (nA, nB) to output (nY) propagation delays

<sup>[2]</sup>  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

<sup>[3]</sup> Typical values are measured at nominal supply voltage ( $V_{CC} = 3.3 \text{ V}$  and  $V_{CC} = 5.0 \text{ V}$ ).

Table 8. Measurement points

Supply voltage	Input	Output
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>
< 2.7 V	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>
2.7 V to 3.6 V	1.5 V	1.5 V
≥ 4.5 V	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>



Test data is given in Table 9.

Definitions test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

 $R_L$  = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

Fig 7. Load circuit for switching times

Table 9. Test data

Supply voltage	Input	
V <sub>CC</sub>	V <sub>I</sub>	t <sub>r</sub> , t <sub>f</sub>
< 2.7 V	V <sub>CC</sub>	≤ 2.5 ns
2.7 V to 3.6 V	2.7 V	≤ 2.5 ns
≥ 4.5 V	V <sub>CC</sub>	≤ 2.5 ns

# 13. Transfer characteristics

Table 10. Transfer characteristics

GND = 0 V; for test circuit, see Figure 7.

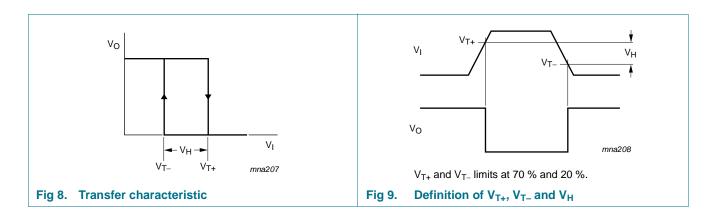
Symbol	Parameter	Conditions	-40	°C to +85	o°C	-40 °C	to +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
	positive-going	see Figure 6						
	threshold voltage	V <sub>CC</sub> = 1.2 V	-	0.70	-	-	-	V
		V <sub>CC</sub> = 2.0 V	8.0	1.10	1.4	8.0	1.4	V
		V <sub>CC</sub> = 2.7 V	1.0	1.45	2.0	1.0	2.0	V
		V <sub>CC</sub> = 3.0 V	1.2	1.60	2.2	1.2	2.2	V
		V <sub>CC</sub> = 3.6 V	1.5	1.95	2.4	1.5	2.4	V
		V <sub>CC</sub> = 4.5 V	1.7	2.50	3.2	1.7	3.2	V
		V <sub>CC</sub> = 5.5 V	2.1	3.00	3.9	2.1	3.9	V

**Table 10. Transfer characteristics** ...continued GND = 0 V; for test circuit, see Figure 7.

Symbol	Parameter	Conditions	-40	°C to +85	5 °C	–40 °C t	Unit	
			Min	Typ[1]	Max	Min	Max	
$V_{T-}$	negative-going	see Figure 6	'					'
	threshold voltage	V <sub>CC</sub> = 1.2 V	-	0.34	-	-	-	V
		V <sub>CC</sub> = 2.0 V	0.3	0.65	0.9	0.3	0.9	V
		V <sub>CC</sub> = 2.7 V	0.4	0.90	1.4	0.4	1.4	V
		V <sub>CC</sub> = 3.0 V	0.6	1.05	1.5	0.6	1.5	V
	$V_{CC} = 3.6 \text{ V}$ $V_{CC} = 4.5 \text{ V}$ $V_{CC} = 5.5 \text{ V}$	V <sub>CC</sub> = 3.6 V	0.8	1.30	1.8	0.8	1.8	V
		V <sub>CC</sub> = 4.5 V	0.9	1.60	2.0	0.9	2.0	V
		V <sub>CC</sub> = 5.5 V	1.2	2.00	2.6	1.2	2.6	V
$V_{H}$	hysteresis voltage	(V <sub>T+</sub> – V <sub>T-</sub> ); see <u>Figure 6</u>						
		V <sub>CC</sub> = 1.2 V	-	0.3	-	-	-	V
		V <sub>CC</sub> = 2.0 V	0.2	0.55	0.8	0.2	8.0	V
		V <sub>CC</sub> = 2.7 V	0.3	0.60	1.1	0.3	1.1	V
		V <sub>CC</sub> = 3.0 V	0.4	0.65	1.2	0.4	1.2	V
		V <sub>CC</sub> = 3.6 V	0.4	0.70	1.2	0.4	1.2	V
		V <sub>CC</sub> = 4.5 V	0.4	0.80	1.4	0.4	1.4	V
		V <sub>CC</sub> = 5.5 V	0.6	1.00	1.5	0.6	1.5	V

<sup>[1]</sup> All typical values are measured at  $T_{amb}$  = 25 °C.

# 14. Waveforms transfer characteristics



### **Quad 2-input NAND Schmitt trigger**

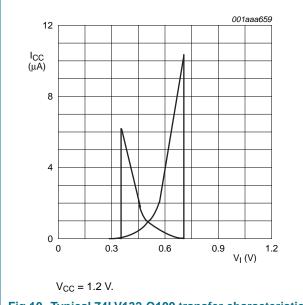


Fig 10. Typical 74LV132-Q100 transfer characteristics

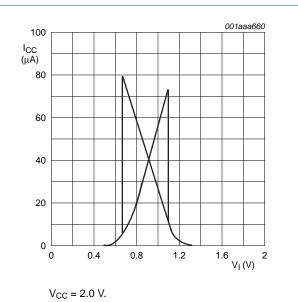
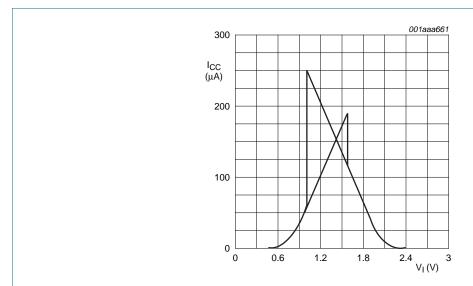


Fig 11. Typical 74LV132-Q100 transfer characteristics

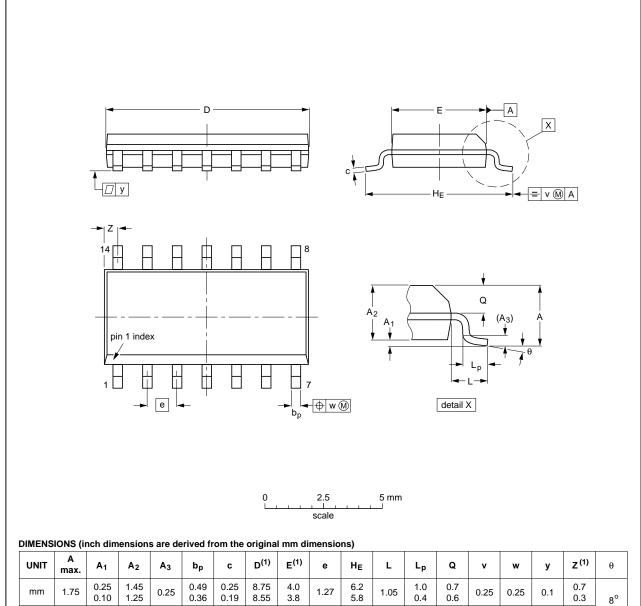


 $V_{CC}$  = 3.0 V. Fig 12. Typical 74LV132-Q100 transfer characteristics

# 15. Package outline

#### SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.35 0.34	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

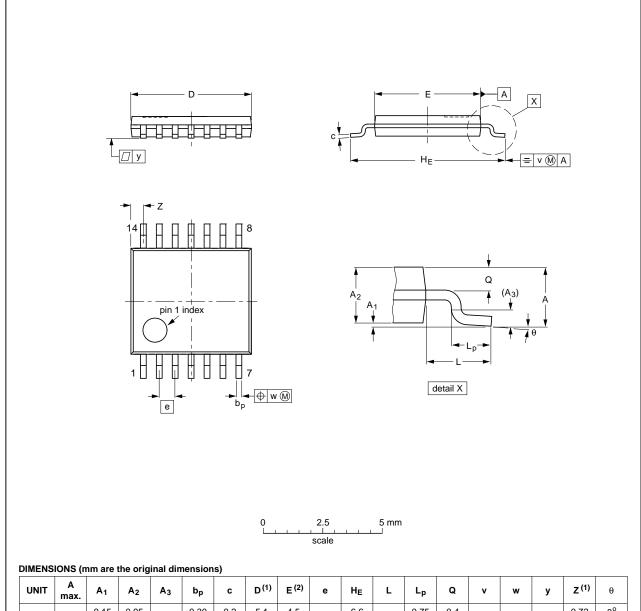
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT108-1	076E06	MS-012				<del>-99-12-27</del> 03-02-19	

Fig 13. Package outline SOT108-1 (SO14)

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



						-,												
UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E (2)	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT402-1		MO-153			$ \  \   \bigoplus   \big($	<del>-99-12-27-</del> 03-02-18	

Fig 14. Package outline SOT402-1 (TSSOP14)

DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm SOT762-1

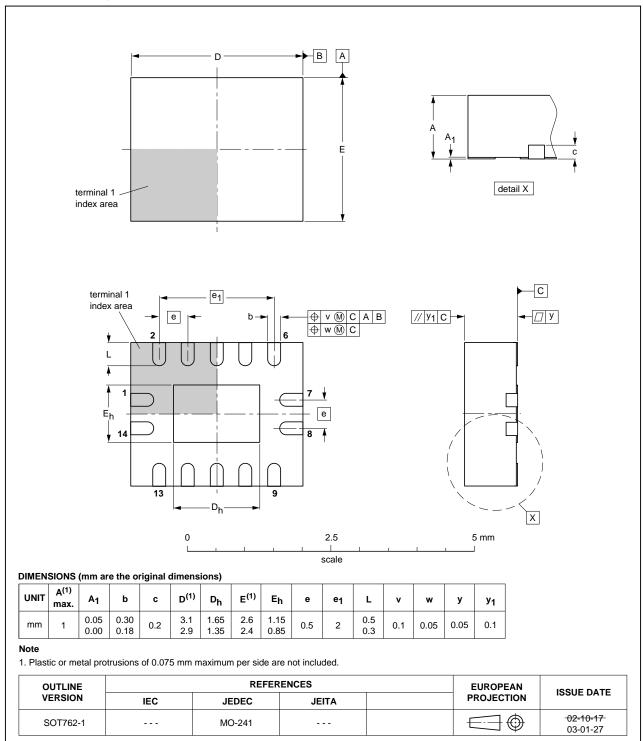


Fig 15. Package outline SOT762-1 (DHVQFN14)

**Quad 2-input NAND Schmitt trigger** 

# 16. Abbreviations

#### Table 11. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

# 17. Revision history

#### Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LV132_Q100 v.1	20131111	Product data sheet	-	-

## 18. Legal information

#### 18.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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